



Optimization of the coupling between Er ions and Si-nc sputtered waveguides

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Outline

Introduction and overview of the issues to address

Material optimisation:

Total lifetime and cooperative up-conversion
Carrier absorption
Er concentration coupled to Si-nc

Conclusions

General Requirements for Optical Gain

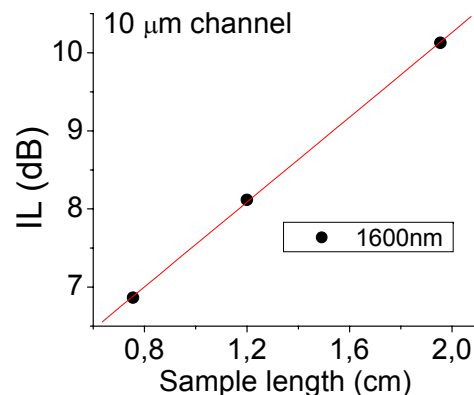
Good waveguides

- Good modal confinement

$$\Gamma = 0.7 - 0.8 \text{ (at } 1.55 \mu\text{m)}$$

- Low waveguide losses (propagation and coupling)

Propagation losses of 2.6dB/cm at 1600nm



Good active material

- As much Er^{3+} as possible (avoiding clustering)

Absorption losses of 6dB/cm

Thus, net gain is possible

➤ **Optimised Si-nc to Er^{3+} coupling to excite all the ions through indirect transfer without damaging the properties of Er^{3+}**

Issues to solve for getting a good active material



Si-nc

+

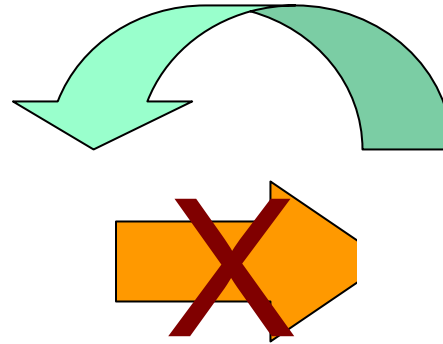
Er³⁺

- Carrier absorption
- Auger deexcitation

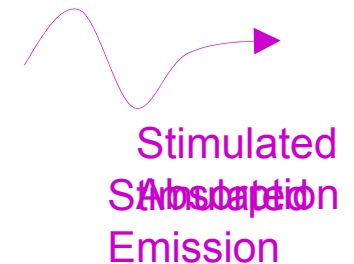
- Non - radiative recombinations (low lifetime)
- Cooperative up-conversion

- Back-transfer
- Distance dependent interaction

Back-transfer

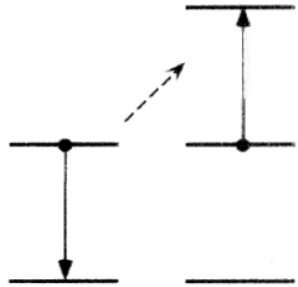


Distance-dependent interaction



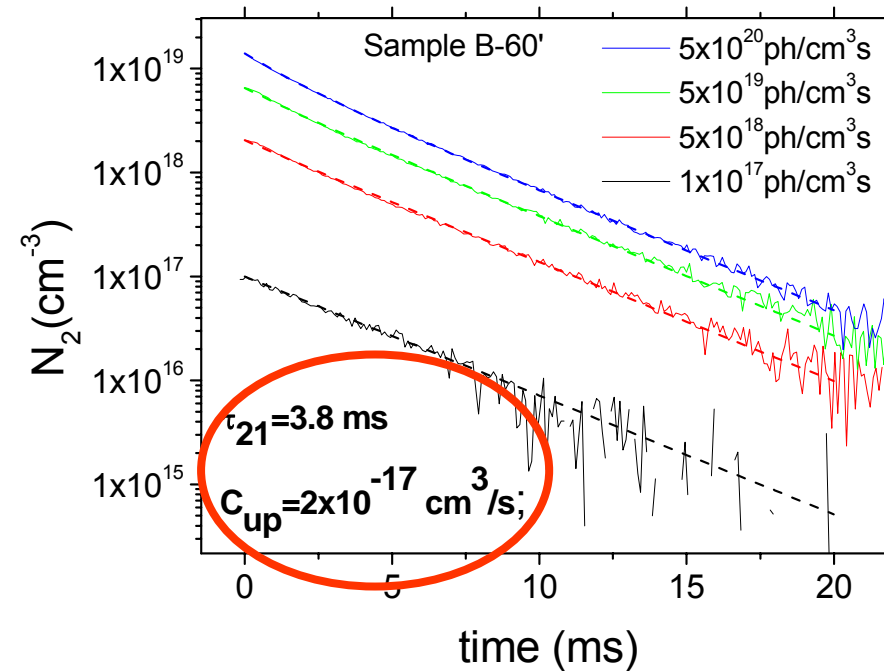
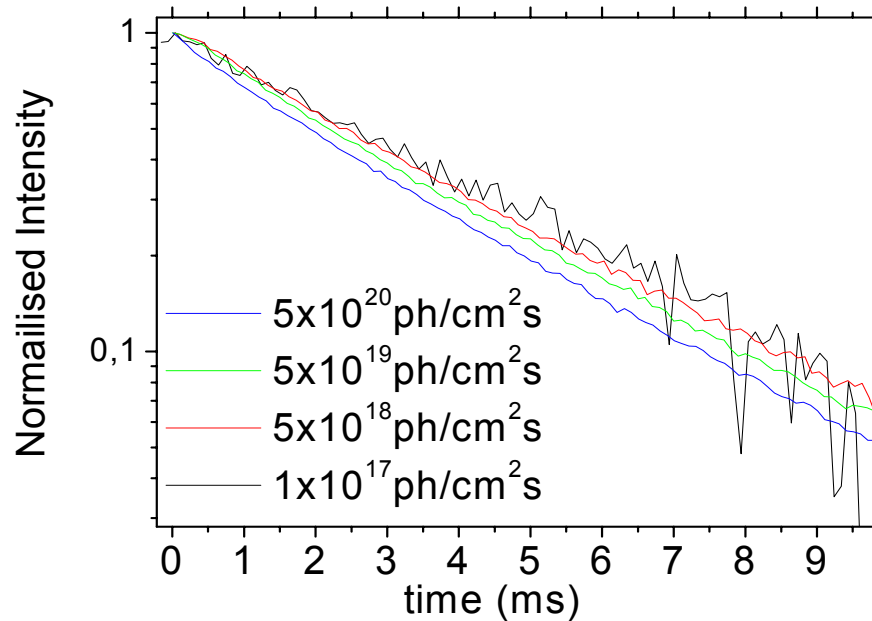


STARTING POINT...



Quantitative measurements of the photon flux emitted from the samples
It is so possible to correlate the number of emitted photons with N_2

$$\frac{dN_2(t)}{dt} = -\frac{N_2(t)}{\tau_{21}} - C_{up} N_2(t)^2$$



σ_{eff} is decreasing with pump flux Φ

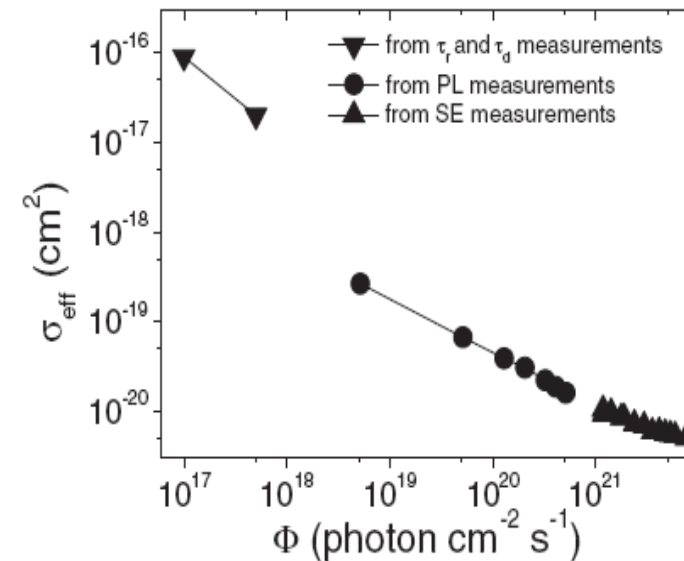
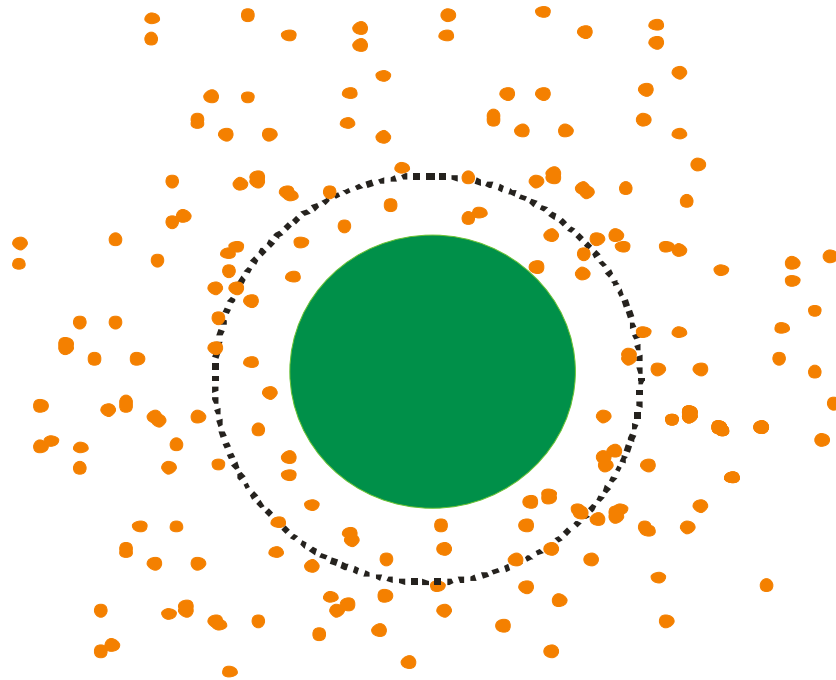


Fig. 9. Effective excitation cross-section of Er^{3+} as a function of the incident flux extracted from lifetime measurements (inverted triangles), from quantitative measurements of the density of excited Er^{3+} ions (circles) and from SE measurements (triangles). The pump wavelength is 488 nm, while the probe wavelength in the region of high pump photon flux was 1535 nm.

D. Navarro-Urrios et al., JJAP 46, 6626 (2007)



Er³⁺ ions near the Si-nc are efficiently coupled to them, whereas Er³⁺ ions far away behave more and more as Er³⁺ in SiO₂ that can be excited only directly.

Model for σ_{exc}

$$\sigma_{exc}(R) = \sigma_o e^{\frac{R-R_{nc}}{R_o}} + \sigma_d$$

We consider that the first Er to be excited and therefore the strongest coupled would be the closest to the Si-nc

Garrido et al., APL 89, 163103 (2006)

Navarro-Urrios et al., JJAP 46, 6626 (2007)

$R_o = 0.5 - 1 \text{ nm}$

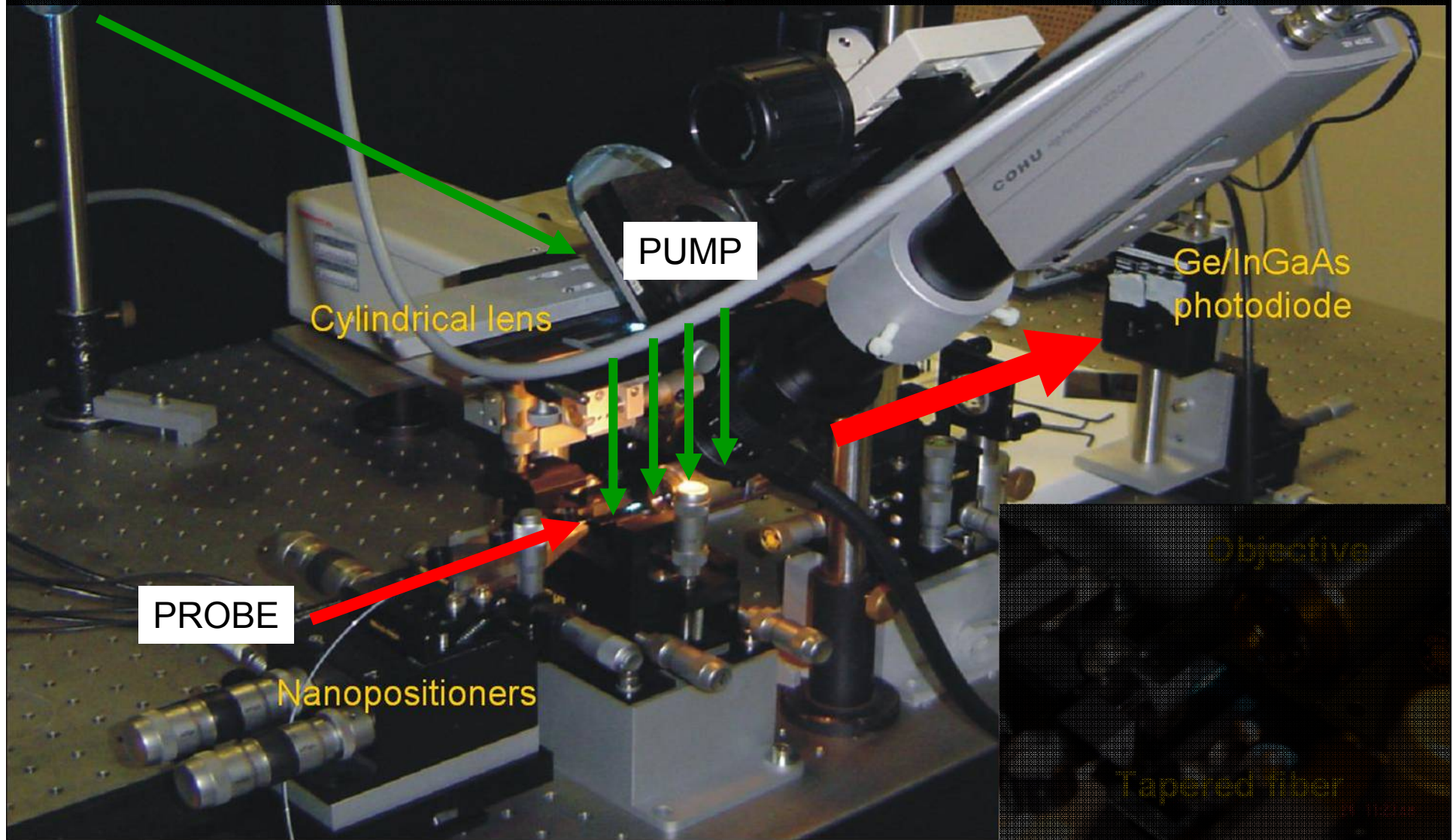
**Short range
interaction**

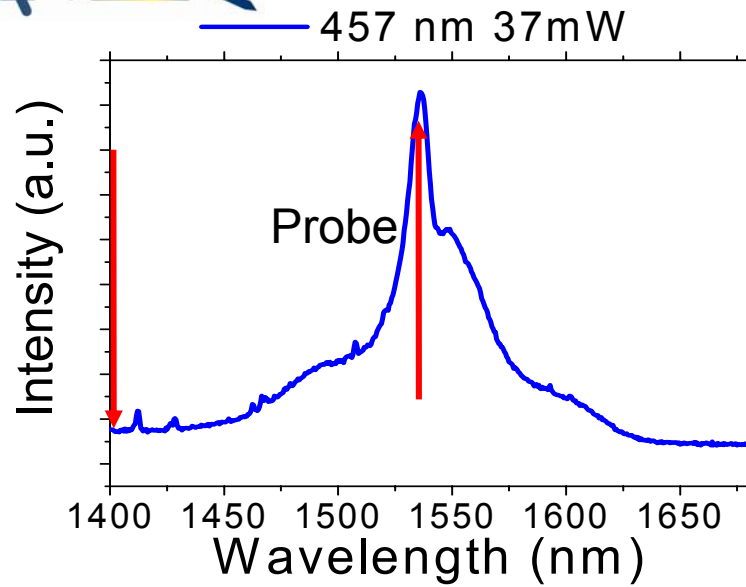
Thus, we were able to excite only 2-3% of the whole erbium population through transfer from Si-nc.

Signal enhancement (Pump&Probe experimental setup)

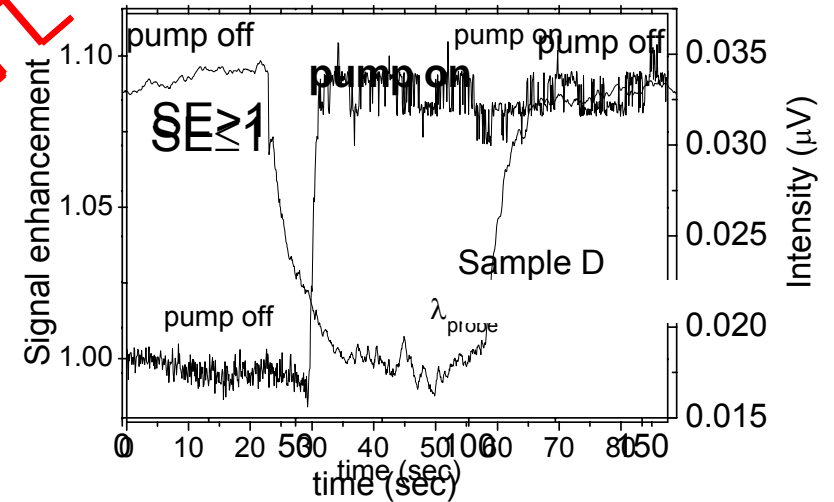
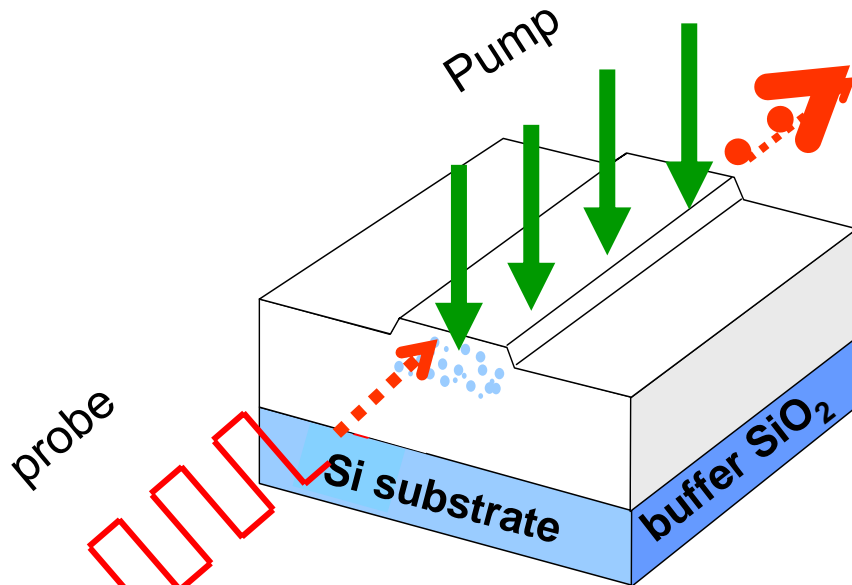
INPUT

OUTPUT





Signal Enhancement Absorption!!



$$\alpha_{CA} = 1 \text{ dB/cm}$$

New run Sample Optimization Deposition parameters



Figures of merit

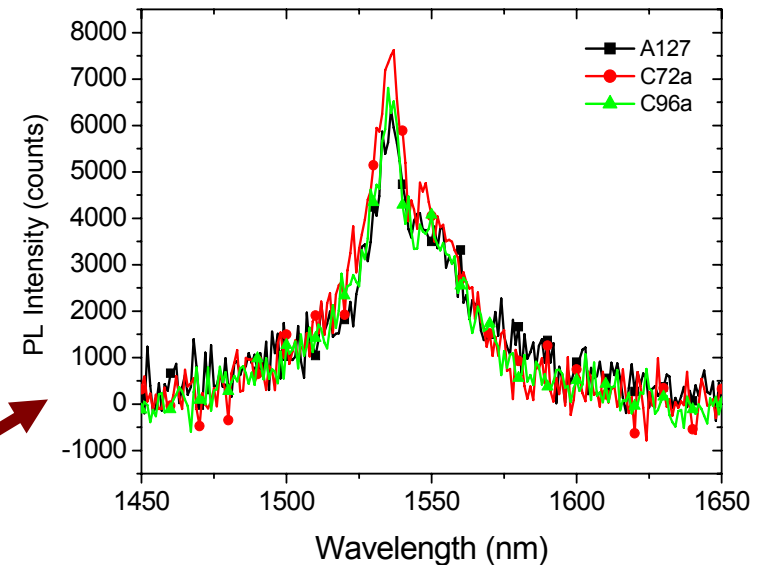
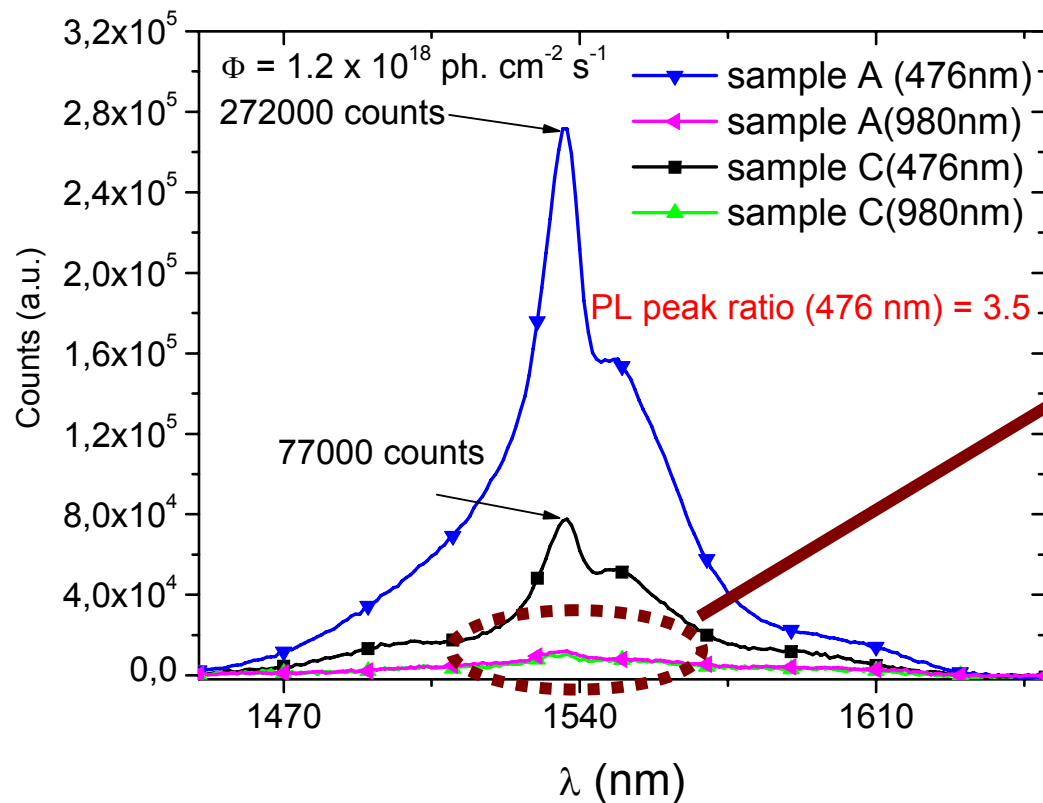
➤ $4I_{13/2} \rightarrow 4I_{15/2}$ PL (@ 1535nm) under non-resonant pumping (476nm)

➤ $4I_{13/2} \rightarrow 4I_{15/2}$ lifetime

➤ Carrier absorption

Sample	Si excess [at %]	Er ³⁺ conc [cm ⁻³]
A	5 ± 2	3.4 ± 0.2 × 10 ²⁰
C	8.5 ± 2.0	4.0 ± 0.4 × 10 ²⁰

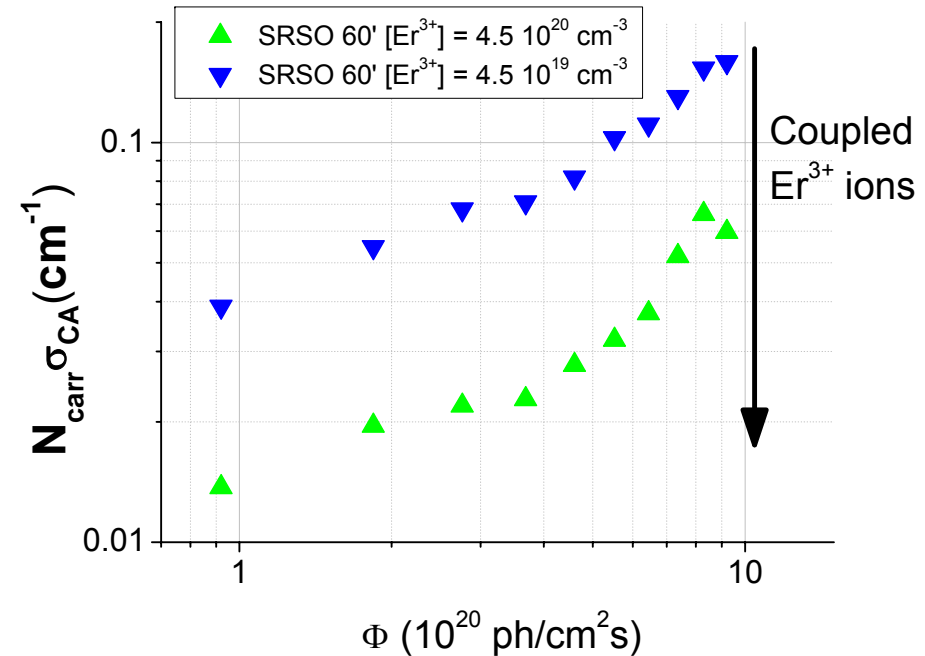
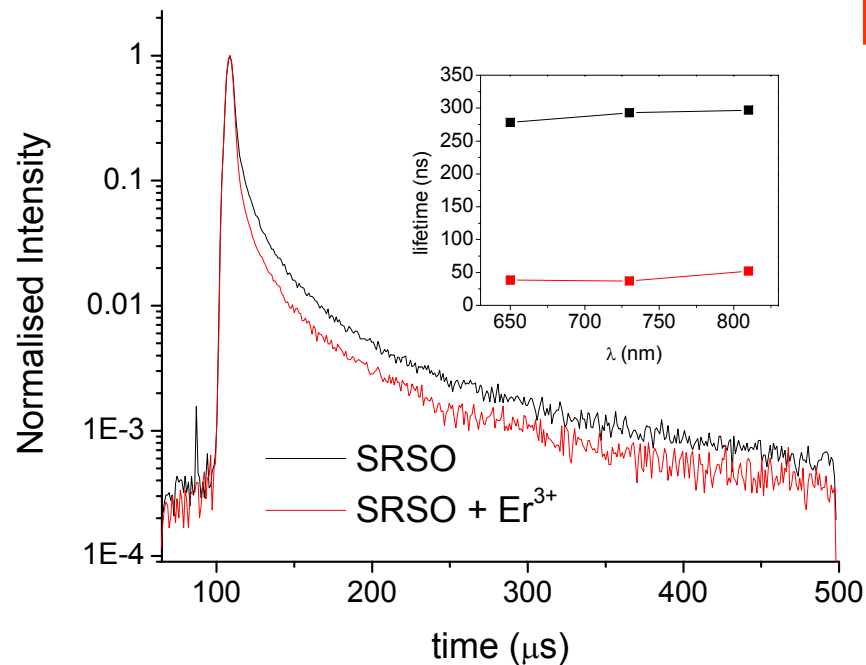
Optimization of the Si/Er ratio



New run is much more intense than best sample of previous run when pumping indirectly, while direct pumping gives the same contribution

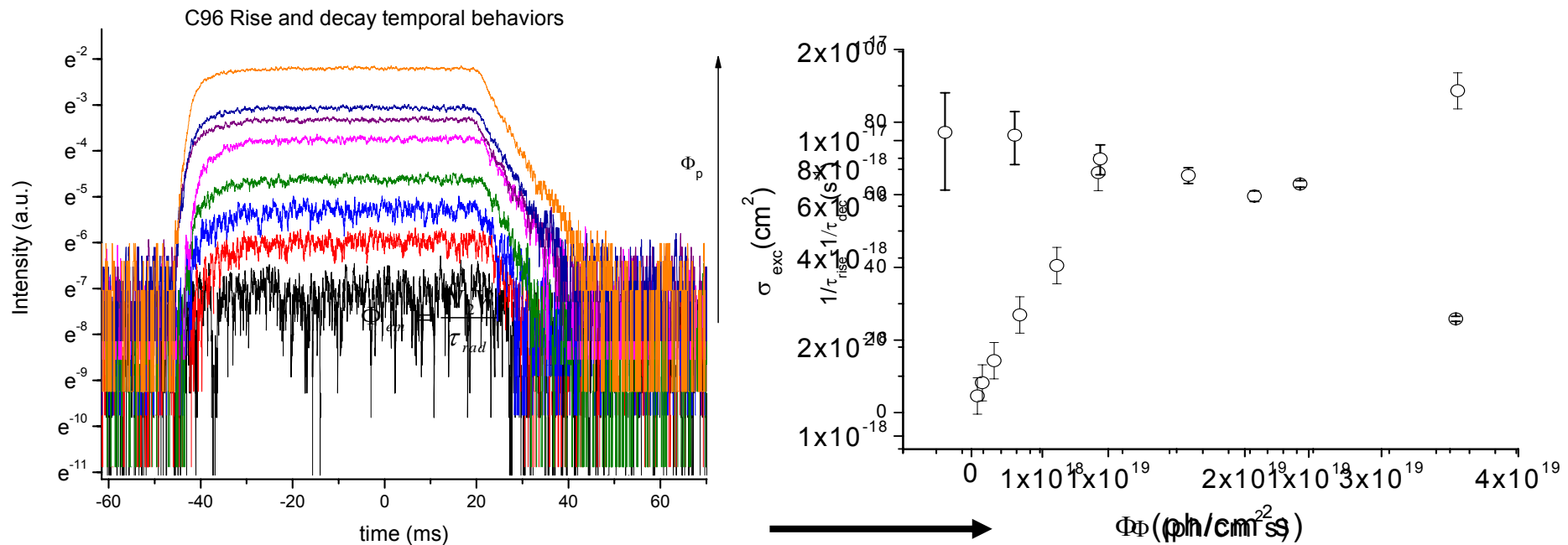
Optimization of the coupling: Minimising Si-nc decay time in presence of Er^{3+}

Bonus!:: Reduction of the CA losses



Optimization of the coupling: Quantification of the erbium coupled to the Si-nc

Lifetimes as a function of the pump photon flux:

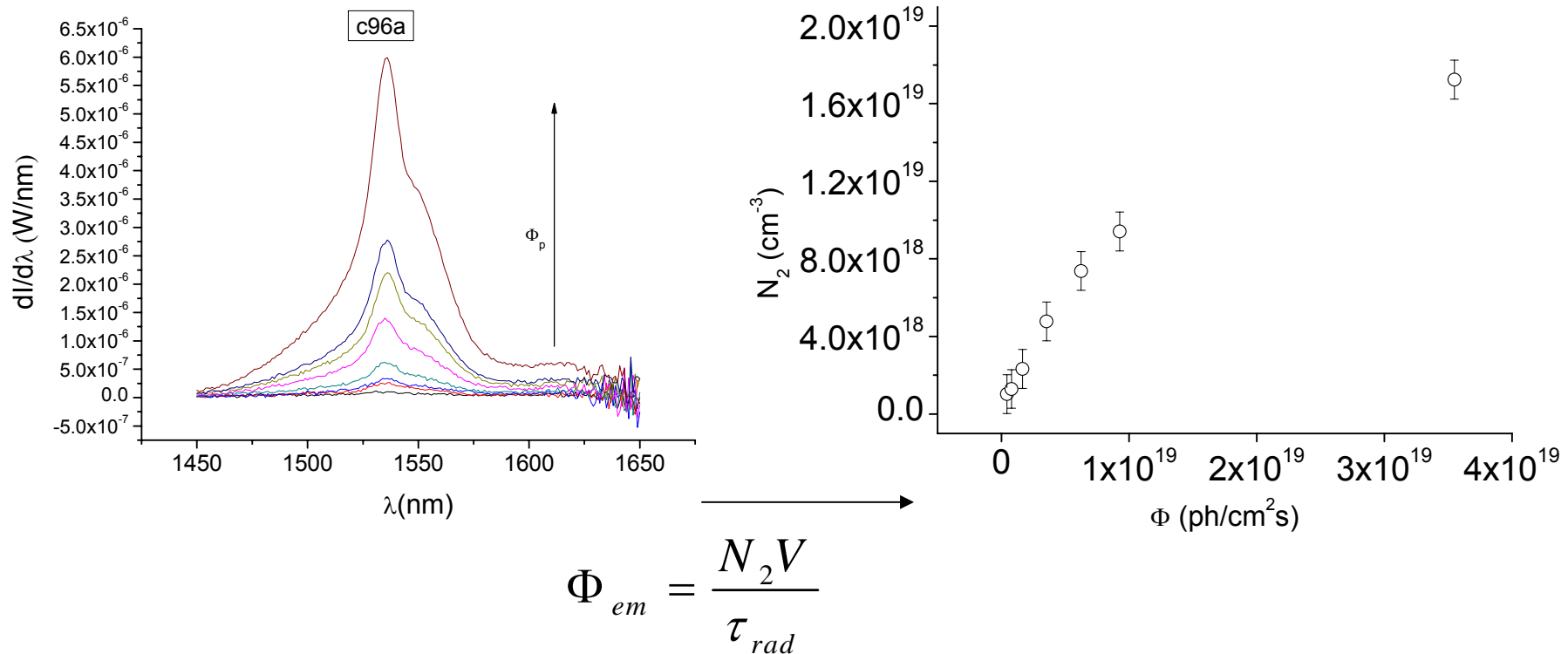


476nm pumping

$$\frac{1}{\tau_r} - \frac{1}{\tau_d} = \sigma_{eff} \Phi$$

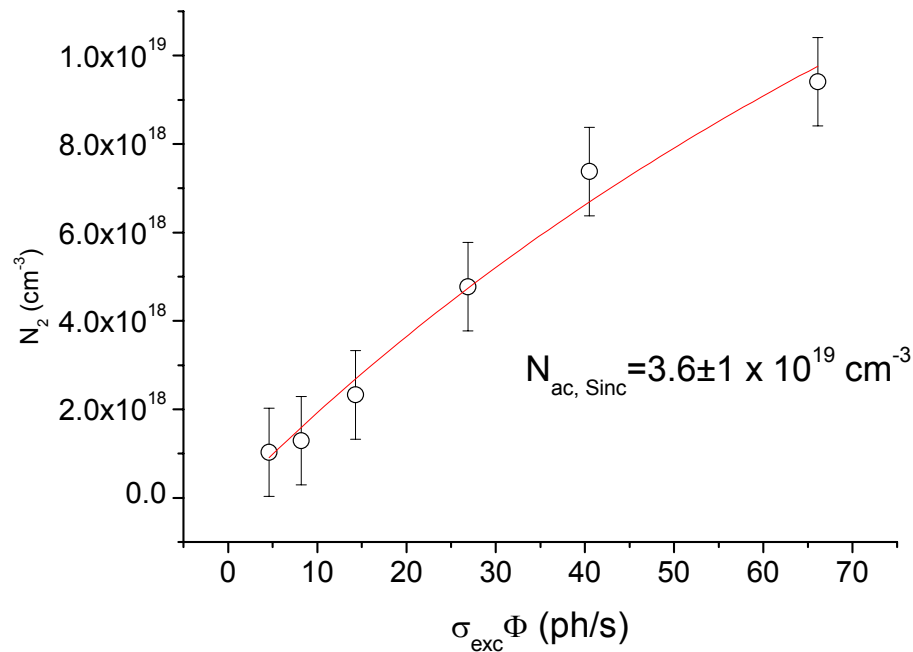
Optimization of the coupling: Quantification of the erbium coupled to the Si-nc

N_2 as a function of the pump photon flux:

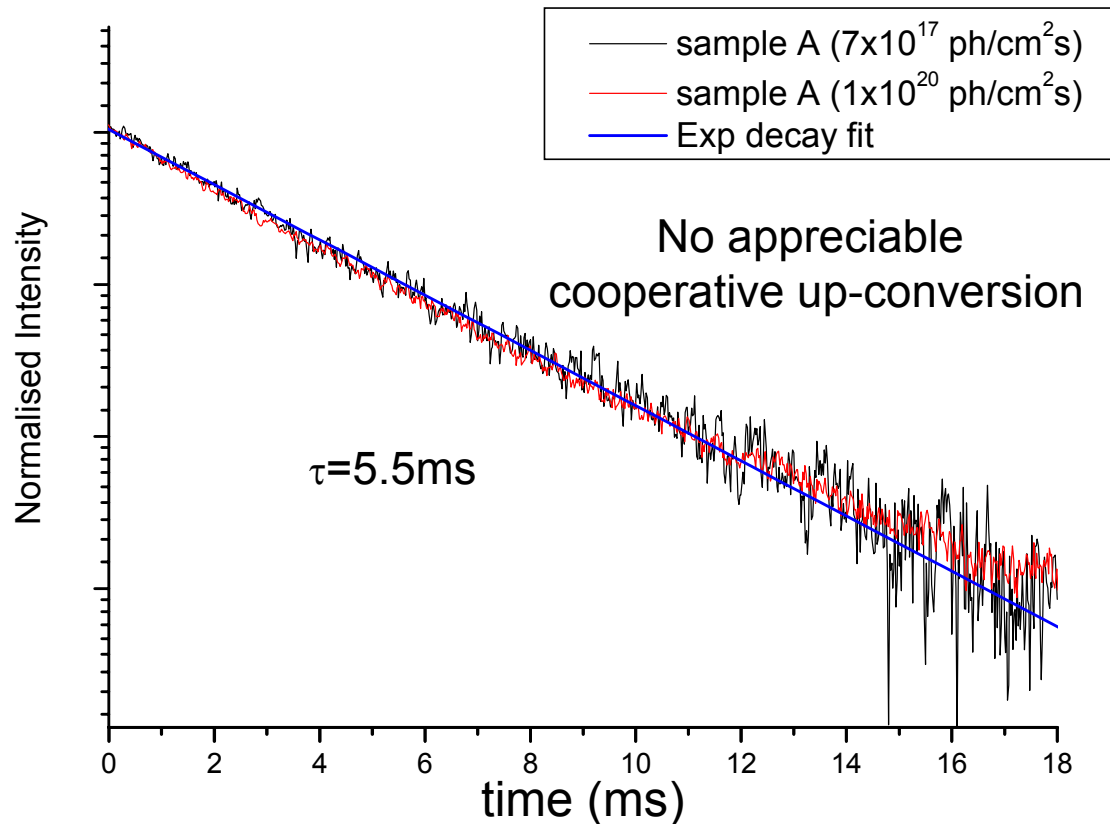


Quantification of the erbium coupled to the Si-nc

$$N_2 = N_{ac, Sinc} \frac{\sigma_{exc} \Phi}{\sigma_{exc} \Phi + 1/\tau_{PL}}$$



Around **23%** of the optically active erbium.

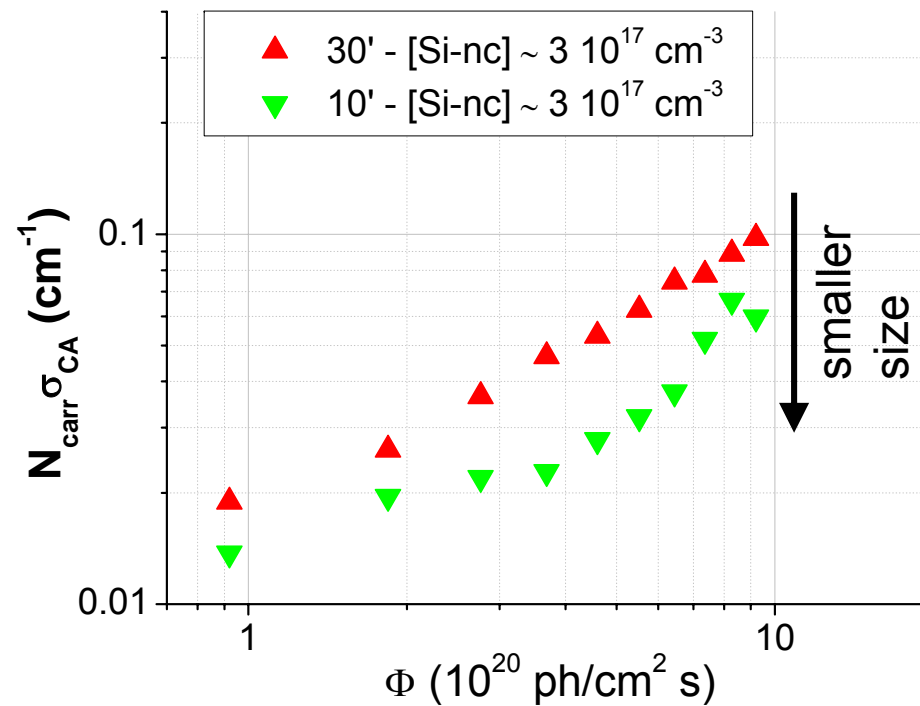


We have increased the total PL lifetime to **5.5 ms** and reduced the cooperative up-conversion to **negligible** values

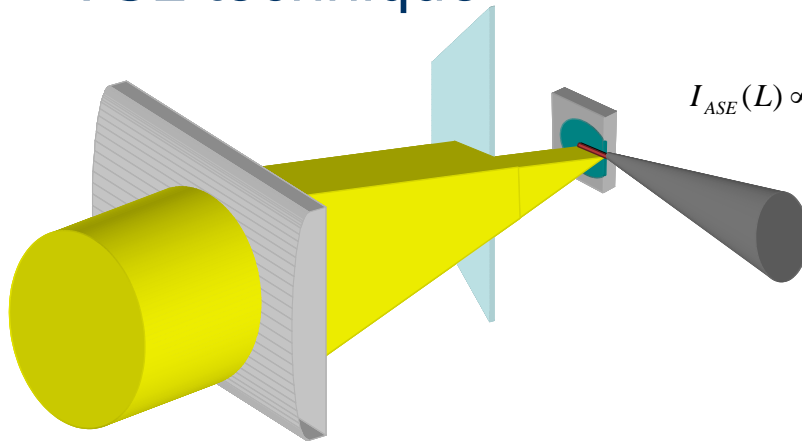
Minimizing Carrier Absorption



By engineering properly the Si-nc size and density it is possible to reduce the CA induced losses.

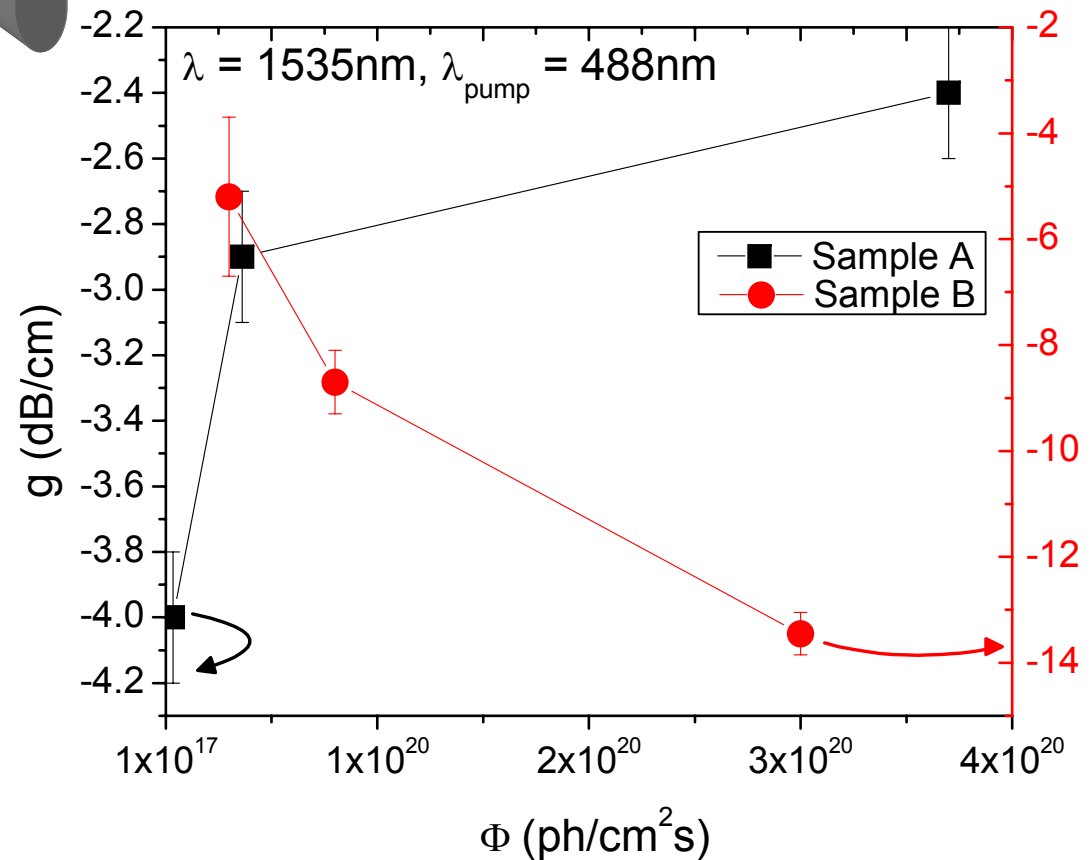


VSL technique

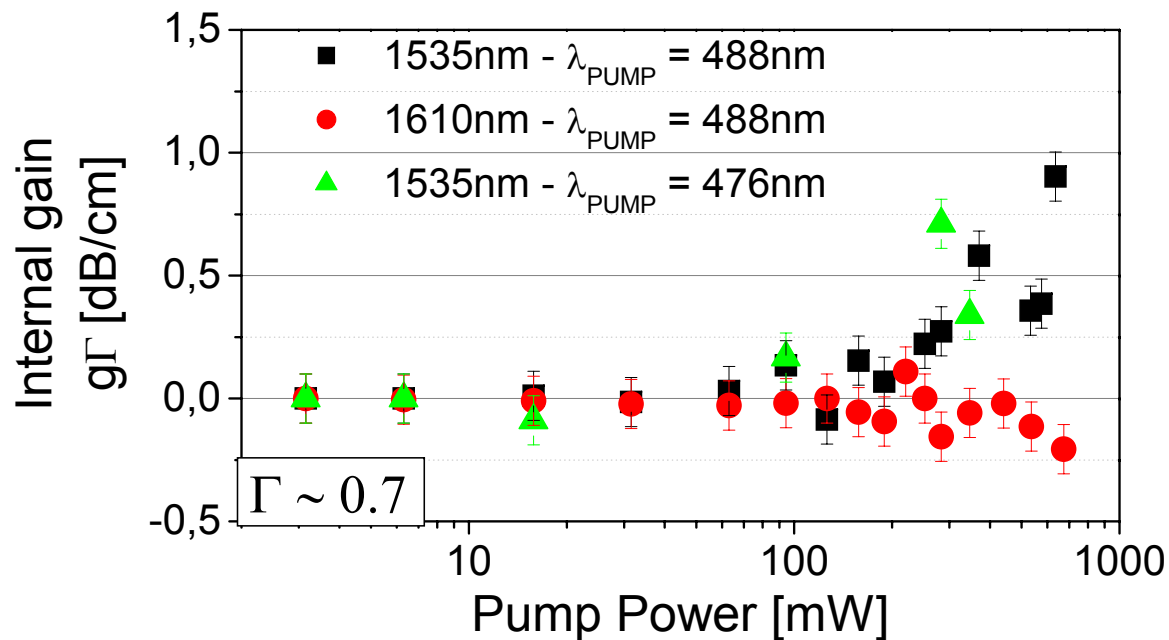


$$I_{ASE}(L) \propto \frac{1}{g} \exp(gL - 1)$$

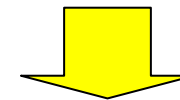
- In sample B the CA losses grow with pump power
- In sample A the CA losses has been reduced and a decreasing of the losses is measured



Pump & probe measurements



$$\frac{g}{\alpha} = \frac{\sigma_{em} N_2}{\sigma_{abs} N_{Er}} \approx \frac{N_2}{N_{Er}}$$



About 25% of Er excited via the Si-nc

Negligible carrier absorption

Comparison



Issue	Last run	New run
Total lifetime	3.8ms	5.5ms
Cooperative up-conversion	$2 \times 10^{17} \text{ cm}^3/\text{s}$	Negligible
Carrier absorption losses	0.9 dB/cm	Negligible
N_{Er} coupled to Si-nc	3%	23%

Conclusions

We have significantly improved our samples in terms of:

- Total lifetime

- Cooperative up-conversion

- Carrier absorption losses

- Concentration of ions coupled to Si-nc

But still it is not enough for achieving the minimum populationinversion needed to obtain **net optical gain** through indirect pumping (we are at 1dB/cm of internal gain).

We have to put most of the Er^{3+} in the close vicinity of a Si-nc



THANK YOU!